



NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



HMC508* Product Page Quick Links

Last Content Update: 08/30/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC508LP5 Evaluation Board.

Documentation

Data Sheet

- HMC508 Data Sheet

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: 32L 5x5mm QFN Package (QTR: 10009 REV: 05)
- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

Technical Articles

- High Performance SiGe PLLs Pair with Low Phase Noise GaAs VCOs for Microwave Radio

Design Resources

- HMC508 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC508 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

* This page was dynamically generated by Analog Devices, Inc. and inserted into this data sheet. Note: Dynamic changes to the content on this page does not constitute a change to the revision number of the product data sheet. This content may be frequently modified.

THIS PAGE INTENTIONALLY LEFT BLANK



MICROWAVE CORPORATION v04.0811



HMC508LP5 / 508LP5E

MMIC VCO w/ HALF FREQUENCY OUTPUT 7.3 - 8.2 GHz

Typical Applications

Low noise MMIC VCO w/Half Frequency, for:

- VSAT Radio
- Point to Point/Multi-Point Radio
- Test Equipment & Industrial Controls
- Military End-Use

Features

Dual Output: $F_o = 7.3 - 8.2$ GHz
 $F_o/2 = 3.65 - 4.1$ GHz

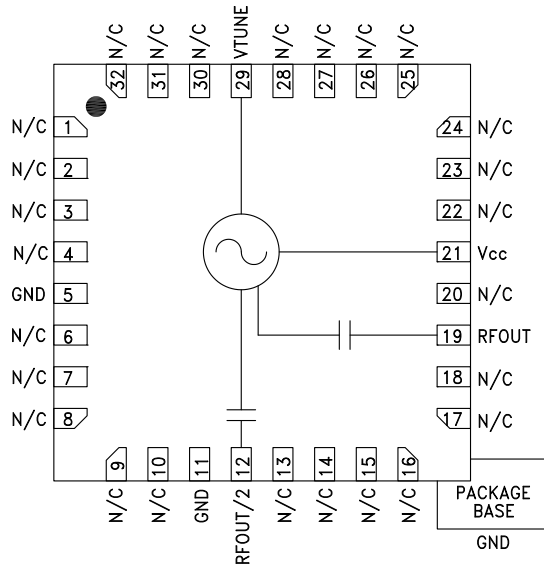
Pout: +15.0 dBm

Phase Noise: -116 dBc/Hz @100 kHz Typ.

No External Resonator Needed

32 Lead 5x5mm SMT Package: 25mm²

Functional Diagram



General Description

The HMC508LP5 & HMC508LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC508LP5 & HMC508LP5E integrate resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +15 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{cc} = +5\text{V}$

Parameter	Min.	Typ.	Max.	Units
Frequency Range	F_o $F_o/2$	7.3 - 8.2 3.65 - 4.1		GHz GHz
Power Output	RFOUT RFOUT/2	+12 +4	+17 +10	dBm dBm
SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5\text{V}$ @ RFOUT		-116		dBc/Hz
Tune Voltage	V_{tune}	2	13	V
Supply Current (I_{cc}) ($V_{cc} = +5.0\text{V}$)	200	240	280	mA
Tune Port Leakage Current ($V_{tune} = 13\text{V}$)			10	μA
Output Return Loss		2		dB
Harmonics/Subharmonics	1/2 2nd 3rd	40 20 35		dBc dBc dBc
Pulling (into a 2.0:1 VSWR)		8		MHz pp
Pushing @ $V_{tune} = 5\text{V}$		10		MHz/V
Frequency Drift Rate		1.0		MHz/ $^\circ\text{C}$

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

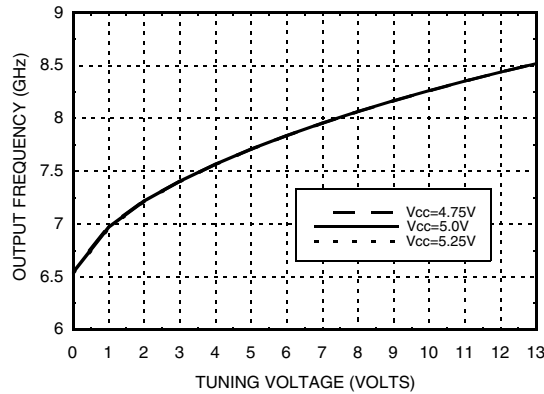
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

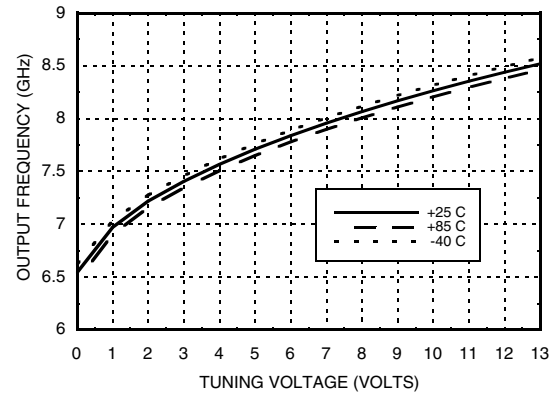
HMC508LP5 / 508LP5E

MMIC VCO w/ HALF FREQUENCY OUTPUT 7.3 - 8.2 GHz

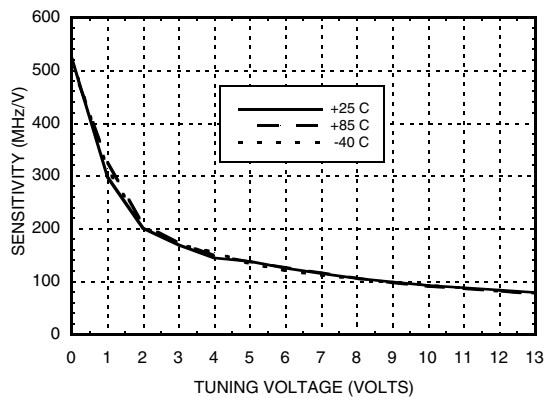
Frequency vs. Tuning Voltage, $T = 25^{\circ}\text{C}$



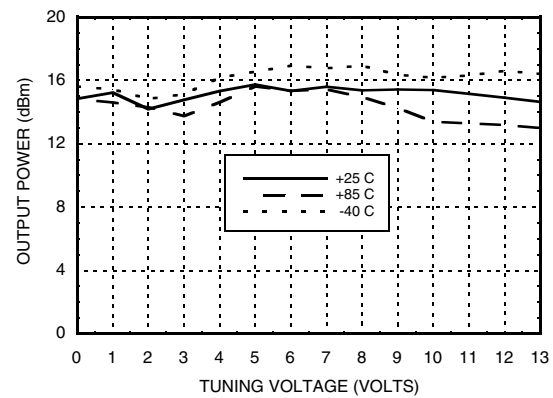
Frequency vs. Tuning Voltage, $V_{cc} = +5V$



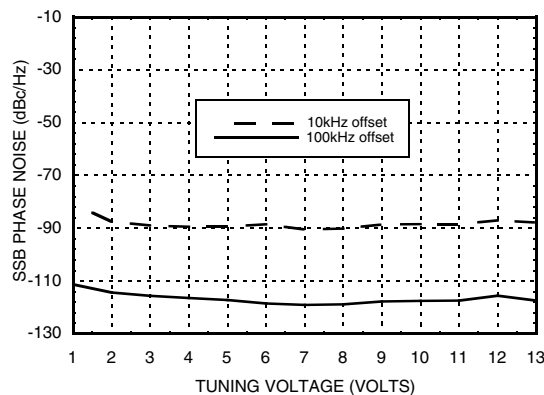
Sensitivity vs. Tuning Voltage, $V_{cc} = +5V$



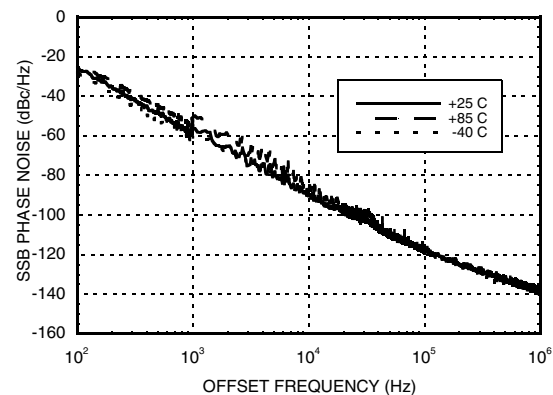
Output Power vs. Tuning Voltage, $V_{cc} = +5V$



SSB Phase Noise vs. Tuning Voltage



SSB Phase Noise @ $V_{tune} = +5V$





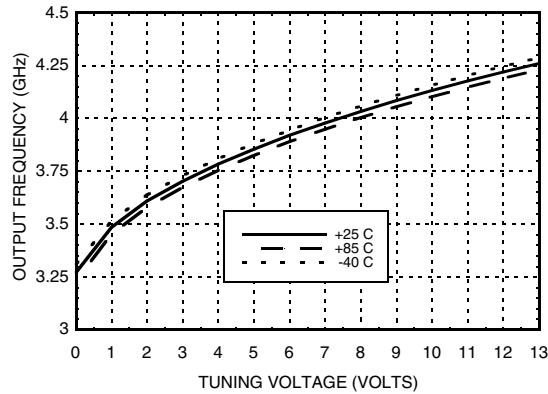
MICROWAVE CORPORATION v04.0811



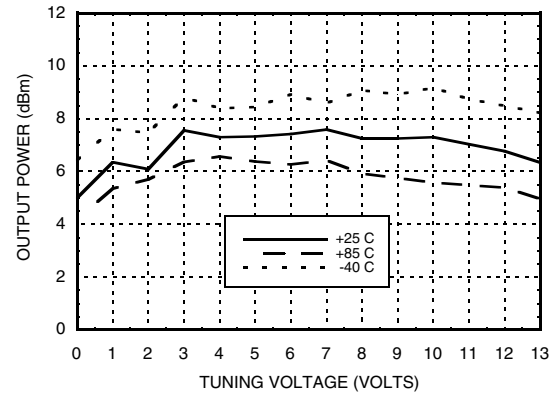
HMC508LP5 / 508LP5E

MMIC VCO w/ HALF FREQUENCY OUTPUT 7.3 - 8.2 GHz

RFOUT/2 Frequency vs. Tuning Voltage, Vcc= +5V



RFOUT/2 Output Power vs. Tuning Voltage, Vcc= +5V



Absolute Maximum Ratings

Vcc	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 28 mW/C above 85 °C)	1.4 W
Thermal Resistance (junction to ground paddle)	35 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	220
5.0	240
5.25	260

Note: VCO will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS



v04 0811



**MMIC VCO w/ HALF FREQUENCY
OUTPUT 7.3 - 8.2 GHz**

TOP VIEW

Dimensions: 32, 25, 24, 17, 9, 16, 1, 8, .201, .193, [5.10, 4.90], .201, .193, [5.10, 4.90], .039, .031, [1.00, 0.80], .003, [0.08], C, .002, .000, [0.05, 0.00], SEATING PLANE, -C-

Labels: HNNN, XXXX, LOT NUMBER

BOTTOM VIEW

Dimensions: .012, .007, [0.30, 0.18], .016, [0.40] REF, .008, [0.20] MIN, .022, .017, [0.56, 0.44], .156, .144, [3.95, 3.65] SQUARE, .140, .135, [3.56, 3.44], .002, .000, [0.05, 0.00], SEATING PLANE, -C-

Labels: PIN 1, Exposed ground paddle must be connected to RF/DC ground

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
5. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
6. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
8. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC508LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 ^[1]	H508 XXXX
HMC508LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[2]	<u>H508</u> XXXX

[3] 4-Digit lot number XXXX



MICROWAVE CORPORATION

v04.0811

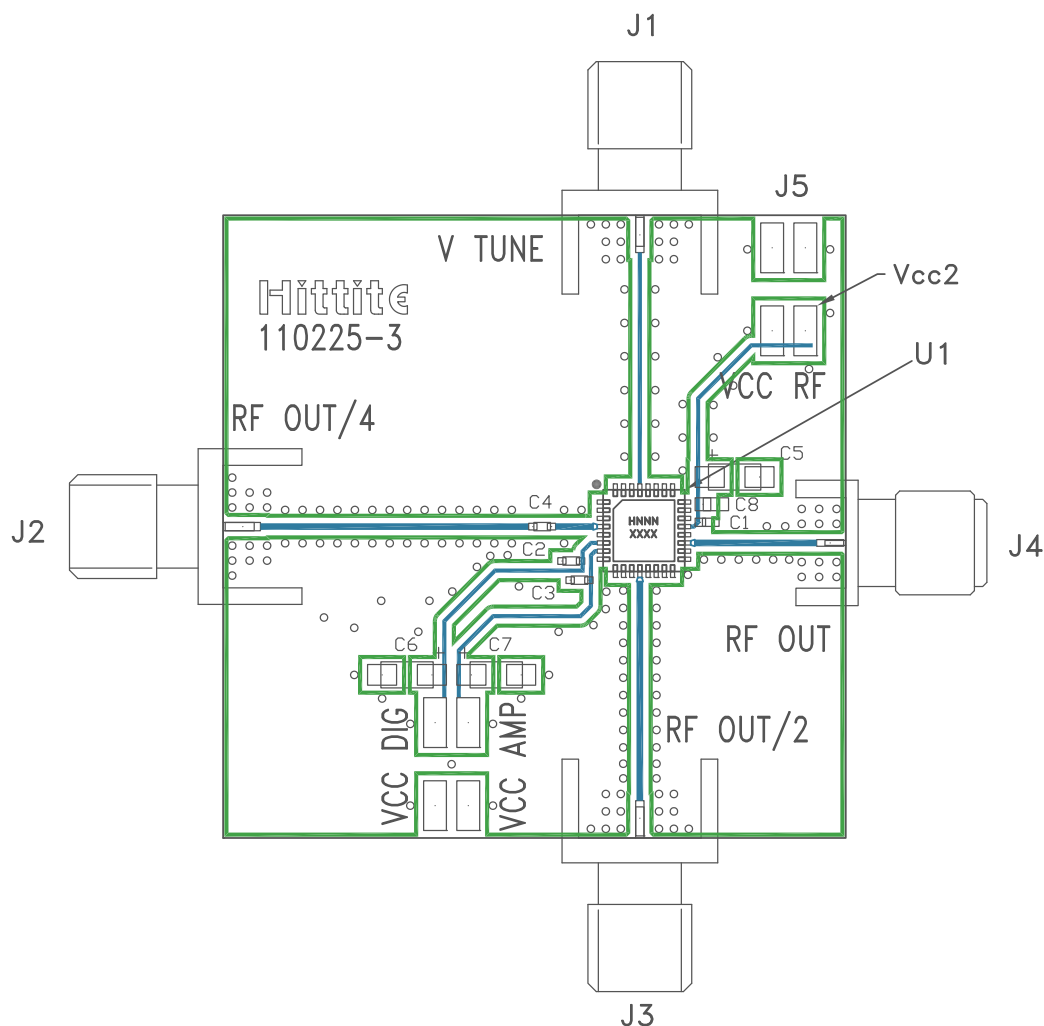
**HMC508LP5 / 508LP5E****MMIC VCO w/ HALF FREQUENCY
OUTPUT 7.3 - 8.2 GHz****Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1 - 4, 6 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/ DC ground. Performance will not be affected.	
12	RFOUT/2	Half frequency output (AC coupled).	
19	RFOUT	RF output (AC coupled).	
21	Vcc	Supply Voltage, +5V	
29	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	

8

VCOS WITH Fo/2 OUTPUT - SMT

Evaluation PCB



List of Materials for Evaluation PCB 110227 [1]

Item	Description
J1 - J4	PCB Mount SMA RF Connector
J5	2 mm DC Header
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4	1,000 pF Capacitor, 0402 Pkg.
C5 - C7	2.2 μ F Tantalum Capacitor
U1	HMC508LP5(E) VCO
PCB [2]	110225 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.